TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIV)

2SK3565

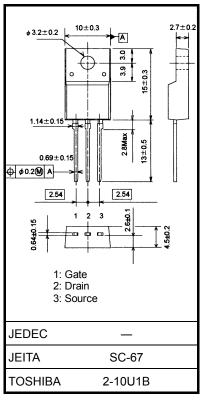
Switching Regulator Applications

Low drain-source ON resistance: R_{DS (ON)} = 2.0 Ω (typ.)

- High forward transfer admittance: $|Y_{fs}| = 4.5 \text{ S}$ (typ.)
- Low leakage current: I_{DSS} = 100 μA (V_{DS} = 720 V)
- Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	900	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V _{DGR}	900	V
Gate-source voltage		V _{GSS}	±30	V
Drain current	DC (Note 1)	۱ _D	5	
	Pulse (t = 1 ms) (Note 1)	I _{DP}	15	A
Drain power dissipation (Tc = 25° C)		PD	45	W
Single pulse avalanche energy (Note 2)		E _{AS}	595	mJ
Avalanche current		I _{AR}	5	А
Repetitive avalanche energy (Note 3)		E _{AR}	4.5	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature range		T _{stg}	-55~150	°C



Weight : 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

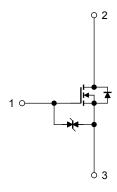
Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	2.78	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}(\text{Initial}), \text{ L} = 43.6 \text{ mH}, \text{ I}_{AR} = 5.0 \text{ A}, \text{ R}_{G} = 25 \Omega$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.



Start of commercial production 2002-06

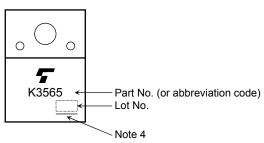
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 25~V,~V_{DS}=0~V$	_		±10	μA
Gate-source brea	akdown voltage	V (BR) GSS	$I_G = \pm 10 \ \mu\text{A}, \ V_{DS} = 0 \ V$	±30		_	V
Drain cut-off curr	ent	I _{DSS}	$V_{DS} = 720 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			100	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	900			V
Gate threshold v	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3 \text{ A}$		2.0	2.5	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 20 V, I_D = 3 A$	2.0	4.5		S
Input capacitance	nput capacitance C _{iss}				1150		
Reverse transfer capacitance		C _{rss}	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz		20		pF
Output capacitance		Coss			100		
Switching time	Rise time	tr	V_{GS} $0 V$ V_{GS} $0 V$		30	_	
	Turn-on time	t _{on}			70	_	20
	Fall time	t _f			60	_	- ns
	Turn-off time	t _{off}	Duty \leq 1%, $t_W=$ 10 μs	_	170	—	
Total gate charge		Qg		_	28		
Gate-source charge		Q _{gs}	$V_{DD}\simeq 400~V,~V_{GS}=10~V,~I_{D}=5~A$		17		nC
Gate-drain charge		Q _{gd}			11		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	5	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_	_	15	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 5 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 5 \text{ A}, V_{GS} = 0 \text{ V},$	_	900	_	ns
Reverse recovery charge	Q _{rr}	dI _{DR} /dt = 100 A/μs	_	5.4	_	μC

Marking

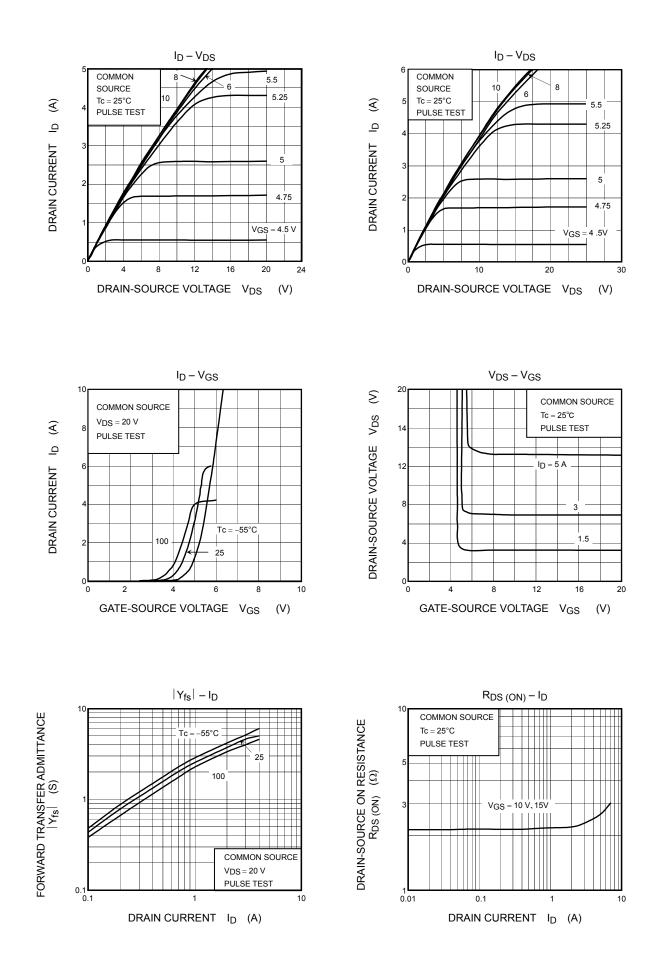


Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

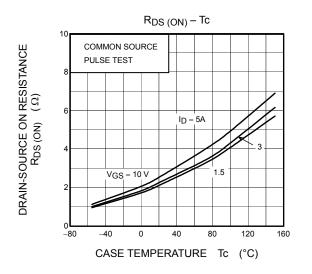
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

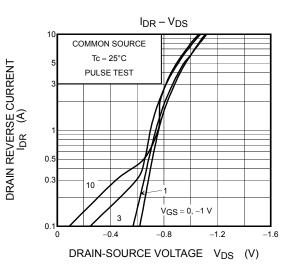
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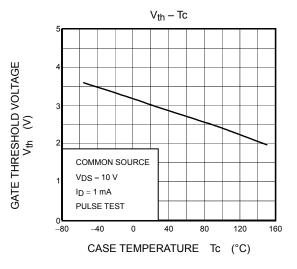


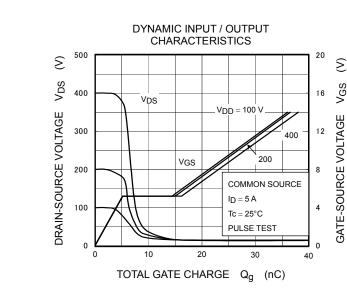
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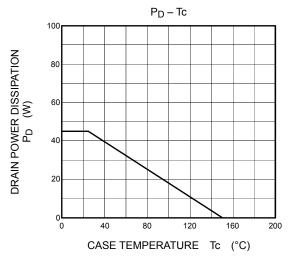


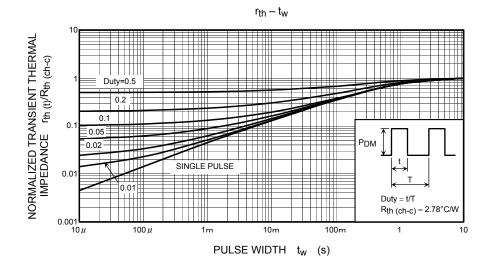


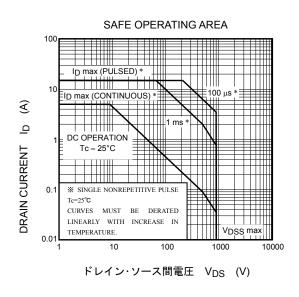
CAPACITANCE - VDS 10000 **1**||| (PF) Ciss 1000 ပ CAPACITANCE 100 COMMON SOURCE VGS = 0 V f = 1 MHz $Tc = 25^{\circ}C$ 10**L** 0.1 10 30 50 3 5 100 DRAIN-SOURCE VOLTAGE VDS (V)

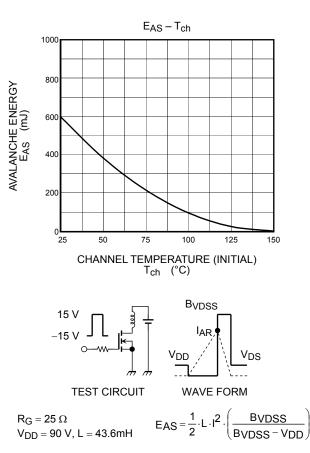












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